

# 43CTQ080/100 43CTQ080/100S 43CTQ080/100-1

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# Technical Data Data Sheet N0701, Rev. A 43CTQ080(100)/43CTQ080(100)S /43CTQ080(100)-1 SCHOTTKY RECTIFIER

## Features

- 150°C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

 43CTQ080(100)
 43CTQ080(100)S
 43CTQ080(100)-1

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#### Maximum Ratings@Tc=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	80(43CTQ080) 100(43CTQ100)	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=102°C, rectangular wave form	20(Per Leg) 40(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	300	А

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# **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per Leg)*	V <sub>F1</sub>	@ 20A, Pulse, T」 = 25 °C @ 40A, Pulse, T」 = 25 °C	0.81 -	0.85 0.98	V
	V <sub>F2</sub>	@ 20A, Pulse, T」 = 125 °C @ 40A, Pulse, T」 = 125 °C	0.69 -	0.72 0.81	V
Reverse Current (Per Leg)*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25 °C	0.0003	1	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 125 °C	0.2	11	mA
Junction Capacitance(Per Leg)	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	515	700	pF
Typical Series Inductance (Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/µs

\* Pulse width < 300  $\mu s, \ duty \ cycle < 2\%$ 

# Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R <sub>0JC</sub>	DC operation	1.6	°C/W
Typical Thermal Resistance Junction to Case(Per Package)	Rejc	DC operation	0.8	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>0JS</sub>	DC operation	0.50	°C/W
Case Style	TO-220AB D <sup>2</sup> PAK TO-262			

# **Tube Specification**

Device	Package	Weight	Shipping
43CTQ	TO-220AB	1.8g	50pcs / tube
43CTQS	D <sup>2</sup> PAK	1.85g	800pcs / reel
43CTQ1	TO-262	1.85g	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# Tube Specification(TO-220AB/TO-262)



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# **Ratings and Characteristics Curves**





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# **Marking Diagram**





# 43CTQ080-1 SSG XXXXX 0

#### Where XXXXX is YYWWL

43	= Forward Current (40A)
С	= Configuration
TQ	= Device Type
080/100	= Reverse Voltage (80V/100V)
S/-1	= Package type
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

#### **Carrier Tape Specification D<sup>2</sup>PAK**



Symbol	Millimeters		
	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

#### **Mechanical Dimensions TO-220AB**





Symbol	Dimensions in millimeters		
	Min	Typical	Max
A	3.56	-	4.83
A1	0.51	-	1.4
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
С	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	9.65	-	10.67
е	-	2.54	-
e1	-	5.08	-
H1	5.84	-	6.86
L	12.7	-	14.73
L1	-	-	6.35
ΦΡ	-	3.56	-
Q	2.54	-	3.43

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# Mechanical Dimensions D<sup>2</sup>PAK



Symbol	Dimensions in millimeters		
Symbol	Min.	Max.	
A	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
e	2.54	BSC	
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	



# **Mechanical Dimensions TO-262**





Queenhal	Millimeters			
Symbol	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
В	1.22	1.37	1.47	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	8.55	8.70	8.85	
E	10.01	10.16	10.31	
E1	9.88	10.08	10.28	
е		2.54		
e1		5.08		
H1	1.17	1.27	1.37	
L	13.00	13.86	14.08	
L1		3.8		
Θ1		5°		
Θ2		<b>4</b> °		
Θ3		4°		
Θ4		10°		



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